

Description

The PAM8904Q is a piezo sounder driver designed for driving a ceramic/piezo sounder or speaker with $18V_{PP}$ from a 3V power supply. A programmable charge pump boost converter allows the PAM8904Q V_{OUT} to operate in 1x, 2x and 3x mode.

The boost converter operates at a fixed frequency of 1.0MHz and provides a 9V output with a minimum number of external components. PAMs unique drive technology ensures minimal inrush current, low EMI and high efficiency.

To ensure maximum efficiency and battery life, the PAM8904Q includes an auto standby feature which puts the device in sleep mode while there is no valid input signal. A forced shutdown is also available to enable the IC only when required.

To help protect the IC and system, the PAM8904Q includes overtemperature shutdown, overcurrent and short circuit protection.

The PAM8904Q is available in a 16 pin U-QFN3030-16 (Type B) package.

The PAM8904Q is qualified to AEC-Q100 Grade 2 and is Automotive Compliant supporting PPAPs.

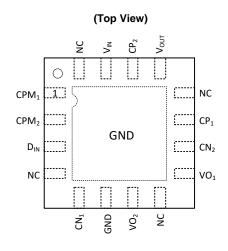
Features

Notes:

- Supply Voltage Range from 2.3V to 5V
- 18VPP Output from a 3V Supply
- Integrated Boost Converter Generates 9V Supply
- Wide Input Signal Capability 20Hz to 300kHz
- Low Current Consumption
- Automatic Standby and Wake-up Control
- Overtemperature Shutdown and Short-Circuit Protection
- Available in Space Saving Packages 16 pin U-QFN3030-16 (Type B) Package with Green Molding
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The PAM8904Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Pin Assignments



U-QFN3030-16 (Type B)

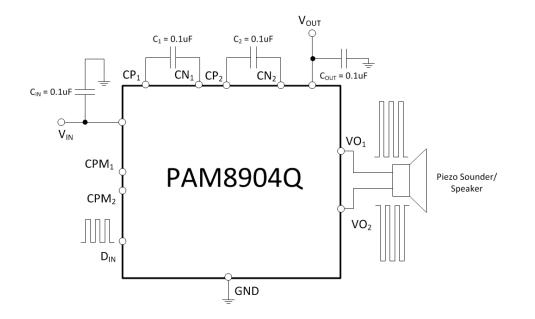
Applications

- Automotive Alarms
- Dash Board Audio
- GPS
- Electric Vehicle Approach Warning
- Automotive Security Device

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit



Pin Descriptions

| Pin Number | Pin Name | I/O/P | Function |
|------------|------------------|-------|--|
| 1 | CPM ₁ | I | Charge pump mode select 1 |
| 2 | CPM ₂ | I | Charge pump mode select 2 |
| 3 | DIN | I | Signal Input |
| 4 | NC | | No Connection |
| 5 | CN1 | I | Capacitor 1 Negative Terminal |
| 6 | GND | Р | Ground |
| 7 | VO ₂ | 0 | Positive Output |
| 8 | NC | | No Connection |
| 9 | VO ₁ | 0 | Negative Output |
| 10 | CN ₂ | I | Capacitor 2 Negative Terminal |
| 11 | CP1 | I | Capacitor 1 Positive Terminal |
| 12 | NC | _ | No Connection |
| 13 | Vout | 0 | Boost Output |
| 14 | CP ₂ | I | Capacitor 2 Positive Terminal |
| 15 | VIN | Р | Power Supply |
| 16 | NC | _ | No Connect |
| PAD | GND | Р | Recommended to connect to GND or No Connection |



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Symbol | Characteristics | Value | Unit |
|-----------------|--|----------------------------------|------|
| VIN | Supply Voltage | -0.3 to +5.5 | V |
| VI | CPM ₁ , CPM ₂ | GND -0.3 to V _{IN} +0.3 | V |
| θја | Thermal Resistance (Junction to Ambient) | 35 | °C/W |
| θ _{JC} | Thermal Resistance (Junction to Case) | 14 | °C/W |
| TJ | Operating Junction Temperature Range | -40 to +150 | °C |
| Tstg | Storage Temperature Range | -65 to +150 | °C |

ESD Susceptibility

| ESD Susceptibility | | | | |
|--------------------|----------------------|-----|----|--|
| HBM | Human Body Model | 8 | kV | |
| MM | Machine Model | 600 | V | |
| CDM | Charged Device Model | 1 | kV | |

Caution: Stresses greater than the 'Absolute Maximum Ratings' specified above, may cause permanent damage to the device. These are stress ratings only; functional operation of the device at conditions between maximum recommended operating conditions and absolute maximum ratings is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

(Semiconductor devices are ESD sensitive and may be damaged by exposure to ESD events. Suitable ESD precautions should be taken when handling and transporting these devices.)

Recommended Operating Conditions (@TA = +25°C, unless otherwise specified.)

| Symbol | Characteristics | | Min | Max | Unit |
|--------|--------------------------------|-------------------------------------|------|----------------------|------|
| VIN | Supply Voltage | | 2.3 | 5.0 | V |
| Vih | High-Level Input Voltage | CPM ₁ , CPM ₂ | 1.2 | V _{IN} +0.3 | V |
| VIL | Low-Level Input Voltage | CPM ₁ , CPM ₂ | -0.3 | +0.4 | V |
| TA | Operating Free-Air Temperature | | -40 | +105 | °C |



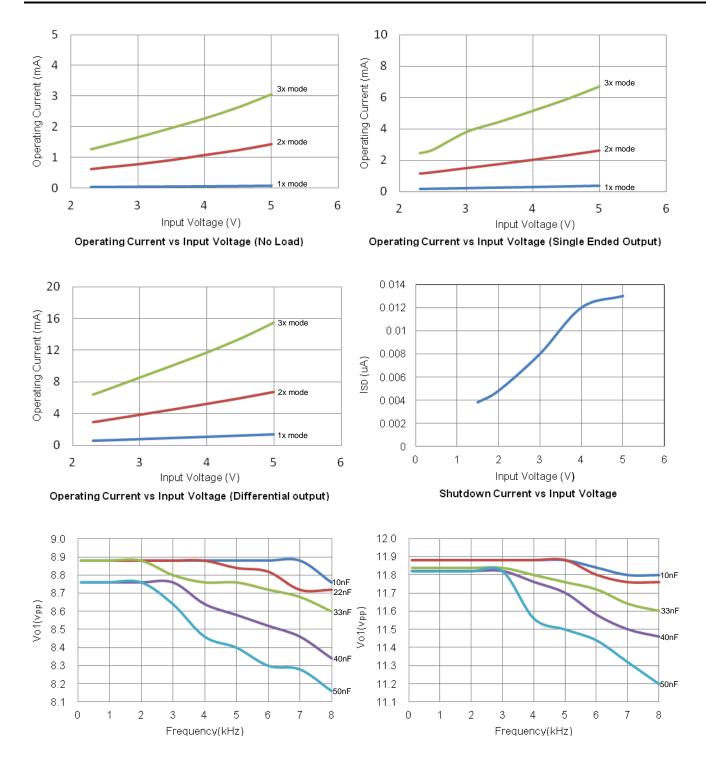
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|-----------------------------------|--|--------------|-------|--------------|------|
| Vout | Output Voltage Range | Note 4 | 2.1 | _ | 12 | V |
| Vout1 | | 1x Mode | 2.8 | — | 3 | V |
| Vout2 | Output Voltage | 2x Mode | 5.2 | _ | 6 | V |
| Vout3 | | 3x Mode | 7.2 | _ | 9 | V |
| IDD11 | | 1x Mode, CPIEZO = No Load | — | 50 | _ | μA |
| IDD12 | Operating Current 1 | 2x Mode, CPIEZO = No Load | _ | 720 | _ | μA |
| IDD13 | | 3x Mode, CPIEZO = No Load | — | 1,700 | _ | μA |
| IDD21 | | 1x Mode, Single-ended application | — | 0.3 | | mA |
| IDD22 | Operating Current 2 | 2x Mode, Single-ended application | — | 1.4 | | mA |
| IDD23 | | 3x Mode, Single-ended application | — | 3.9 | | mA |
| IDD31 | | 1x Mode, Differential application | — | 0.9 | | mA |
| I _{DD32} | Operating Current 3 | 2x Mode, Differential application | — | 3.8 | | mA |
| I _{DD33} | | 3x Mode, Differential application | _ | 8.5 | | mA |
| I _{SD} | Shutdown Current | $D_{IN} = 0V$ | _ | | 1 | μA |
| f _{IN} | Input Frequency | Rectangular pulse on DIN | 0.02 | | 300 | kHz |
| fosc | Oscillating Frequency | — | | 1 | | MHz |
| ton1 | | 1x Mode, From D _{IN} signal High to 90% Vout steady state | _ | 270 | _ | μs |
| t _{ON2} | V _{OUT} Start Delay Time | 2x Mode, From D_{IN} signal High to 90% V_{OUT} steady state | _ | 320 | _ | μs |
| ton3 | | 3x Mode, From D _{IN} signal High to 90% V _{OUT} steady state | _ | 350 | _ | μs |
| toff | Shutdown Delay Time | DIN = H- >L | _ | 42 | | ms |
| lsc | Output Short-Circuit Current | — | _ | 40 | | mA |
| OTP | Thermal Shutdown | Junction temperature | _ | +150 | | °C |
| OTP _{HYS} | Thermal Shutdown Hysteresis | — | — | +37 | _ | °C |
| VIH | Control Terminal Voltage H | CPM ₁ , CPM ₂ , D _{IN} pins | 0.8 x Vin | _ | Vin | V |
| VIL | Control Terminal Voltage L | CPM ₁ , CPM ₂ , D _{IN} pins | 0 | _ | 0.2 x Vin | V |
| I _{IH1} | Control Terminal Current 1 | $D_{IN} = 3V$ | _ | _ | 1 | μA |
| I _{IH2} | Control Terminal Current 2 | $VCPM_1$, $VCPM_2 = 3V$, $D_{IN} = 3V$ | _ | | 1 | μA |
| I _{IH3} | Control Terminal Current 3 | | | _ | 1 | μA |
| CL | Capacitive Load | _ | _ | 15 | 50 | nF |

Note: 4. It is possible to drive V_{OUT}, VO₁ and VO₂ to 3x V_{DD}. A supply voltage of 4V of more should not be used in 3x mode as this will exceed the maximum output voltage rating.

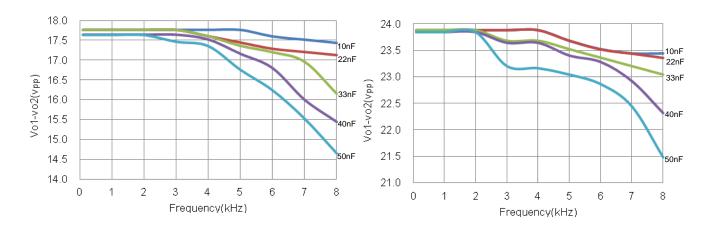


Performance Characteristics (@T_A = +25°C, V_{IN} = 3.0V, C_{Piezo} = 15nF, f_{DIN} = 4kHz, unless otherwise specified.)





Performance Characteristics (continued. @T_A = +25°C, VIN = 3.0V, CPiezo = 15nF, fDIN = 4kHz, unless otherwise specified.)





Application Information

Charge Pump Mode Setting

The Charge Pump Mode (CPM) pins CPM₁ and CPM₂ are used to set the charge pump into mode 1x V_{DD}, 2x V_{DD}, 3x V_{DD} or they can be used to put the PAM8904Q in to a forced low current shutdown mode.

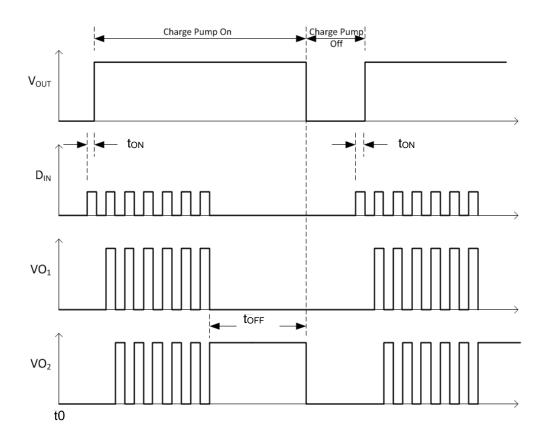
| DIN | CPM ₁ | CPM ₂ | MODE |
|-----|------------------|------------------|---------------|
| 0 | — | | Shutdown Mode |
| 1 | 0 | 0 | Shutdown Mode |
| 1 | 0 | 1 | 1x Mode |
| 1 | 1 | 0 | 2x Mode |
| 1 | 1 | 1 | 3x Mode |

Care must be taken when using the 3x mode with a V_{DD} supply of 4V or more as this will force the V_{OUT} to exceed its maximum specification. The table shows the safe operating range of the PAM8904Q.

| VDD Range | Mode | |
|--------------|----------------|--|
| 2.3V to 3.9V | 1x, 2x and 3x | |
| 4.0V to 5.0V | 1x and 2x only | |

Timing Chart and Device Operation

When one or both of the CPM pins are pulled high, the device enters normal operation mode, refer to the above table for the mode selection. Once the PAM8904Q senses a valid signal on the D_{IN} pin, the charge pump will start and provide the desired voltage on the V_{OUT} pin and the output drive VO_1 and VO_2 start to function after time t_{ON} which is typically between 270µs and 350µs depending on the mode chosen. Once the input signal on D_{IN} is removed, the PAM8904Q senses this and waits typically 42ms to ensure the signal has been removed. If there is no further valid signal within the time period t_{OFF} , the PAM8904Q enters into a low current standby mode.



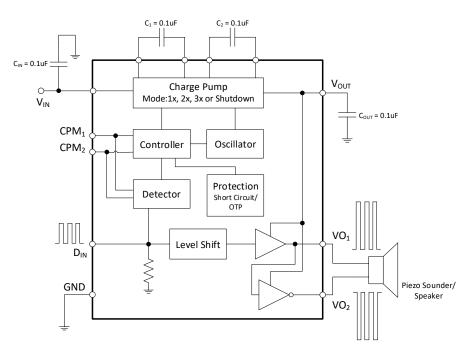


Application Information (continued)

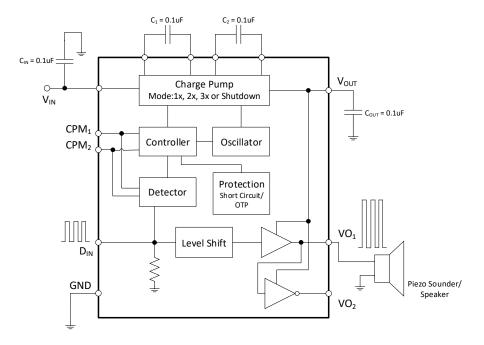
Output Configuration

The PAM8904Q is able to be configured either in a differential or a single ended configuration.

Differential Output Typical Application Circuit



Single Ended Output Typical Application Circuit



When using the PAM8904Q with a single ended output, the VO₂ pin should be left open circuit.



Application Information (continued)

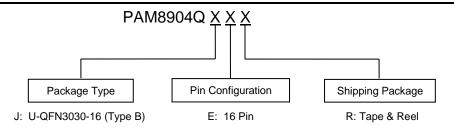
Short-Circuit Protection

The PAM8904Q has short circuit protection circuitry on the outputs to prevent damage. Once a short circuit is detected on the outputs the chip will limit the total current to protect the output device. This is not a latched fault; once the short is removed the normal operation is restored.

Thermal Protection

If the junction temperature of the PAM904Q exceeds +150°C the device will enter overtemperature shutdown. The outputs and the charge pump will be switched off. Once the junction temperature cools down to its normal operating condition, the IC will re-start automatically.

Ordering Information



| Part Number Package Package Type Code (Notes 5 & 6) | | 7" Тар | Qualification | | |
|--|---|-----------------------|--------------------|----------|----------------------|
| | | Quantity | Part Number Suffix | (Note 7) | |
| PAM8904QJER | J | U-QFN3030-16 (Type B) | 3,000/Tape & Reel | R | Automotive Compliant |

Notes: 5. Pad layout shown at http://www.diodes.com/package-outlines.html.

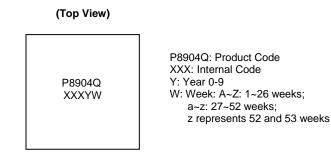
For Tape and reel information see https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.
PAM8904Q has been qualified to AEC-Q100 grade 2 and is classified as "Automotive Compliant" supporting PPAP documentation. Automotive, AEC-Q100 and standard products are electrically and thermally the same, except where specified.

For more information, please refer to https://www.diodes.com/quality/product-definitions/.

See PAM8904 datasheet for commercial qualified versions.

Marking Information

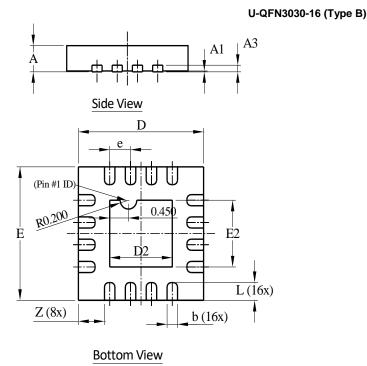
U-QFN3030-16 (Type B)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

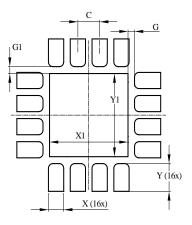


| U-QFN3030-16 (Type B) | | | | | |
|--------------------------|----------------------|------|-------|--|--|
| Dim | Dim Min Max Typ | | | | |
| Α | 0.55 | 0.65 | 0.60 | | |
| A1 | 0 | 0.05 | 0.02 | | |
| A3 | | | 0.15 | | |
| b | 0.18 | 0.28 | 0.23 | | |
| D | 2.95 | 3.05 | 3.00 | | |
| D2 | 1.40 | 1.60 | 1.50 | | |
| E | 2.95 | 3.05 | 3.00 | | |
| E2 | 1.40 | 1.60 | 1.50 | | |
| е | | _ | 0.50 | | |
| L | 0.35 | 0.45 | 0.40 | | |
| Z | | _ | 0.625 | | |
| All | All Dimensions in mm | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-QFN3030-16 (Type B)



| Dimensions | Value |
|------------|---------|
| Dimensions | (in mm) |
| С | 0.500 |
| G | 0.150 |
| G1 | 0.150 |
| Х | 0.350 |
| X1 | 1.800 |
| Y | 0.600 |
| Y1 | 1.800 |



IMPORTANT NOTICE

1. DIODES INCORPORATED AND ITS SUBSIDIARIES ("DIODES") MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes products. Diodes products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of the Diodes products for their intended applications, (c) ensuring their applications, which incorporate Diodes products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.

3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.

4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.

5. Diodes products are provided subject to Diodes' Standard Terms and Conditions of Sale (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

6. Diodes products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.

7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.

8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

Copyright © 2021 Diodes Incorporated

www.diodes.com